	Application No.	Applicant(s)
Notice of Allowability	10/798,571	NAKAJIMA ET AL.
	Examiner	Art Unit
	Mai-Huong Tran	2818
The MAILING DATE of this communication appears on the cover sheet with the correspondence address All claims being allowable, PROSECUTION ON THE MERITS IS (OR REMAINS) CLOSED in this application. If not included herewith (or previously mailed), a Notice of Allowance (PTOL-85) or other appropriate communication will be mailed in due course. THIS NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RIGHTS. This application is subject to withdrawal from issue at the initiative of the Office or upon petition by the applicant. See 37 CFR 1.313 and MPEP 1308.		
1. This communication is responsive to 3/12/04.		
2. The allowed claim(s) is/are <u>25-35</u> .		
3. The drawings filed on 12 March 2004 are accepted by the Examiner.		
<ul> <li>4.  Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). <ul> <li>a)</li></ul></li></ul>		
	6.  Interview Summary Paper No./Mail Da 7.  Examiner's Amend 8.  Examiner's Statem 9.  Other	ate
Supervisory Patent Examiner Technology Center 2800		

## **DETAILED ACTION**

## Examiner's Amendment.

An examiner's amendment to the record appears below. Should the changes and/or additions be unacceptable to applicant, an amendment may be filed as provided by 37 CFR 1.312. To ensure consideration of such an amendment, it MUST be submitted no later than the payment of the issue fee.

Cancel claims 1-24.

## Reason for allowance

The following is an examiner's statement of reason for allowance: None of the references of record teaches or suggests the claimed Magnetic Storage Apparatus Having Dummy Magnetoresistive Effect Element and Manufacturing Method Thereof having a first magnetoresistive effect element which functions as a memory element by patterning the magnetoresistive effect film of the memory cell portion into the first shape by using the first cap layer, and forming a second magnetoresistive effect element which functions as a dummy by patterning the magnetoresistive effect film of the peripheral circuit portion into the second shape by using the second cap layer; forming a first metal layer by patterning the first metal material film of the memory cell portion into a third shape, and forming a second metal layer by patterning the first metal material film of the peripheral circuit portion into a fourth shape.

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Any comments considered necessary by applicant must be submitted no later than

the payment of the issue fee and, to avoid processing delays, should preferably

accompany the issue fee. Such submissions should be clearly labeled "Comments on

Statement of Reasons for Allowance".

Conclusion

Any inquiry concerning this communication or earlier communications from the

examiner should be directed to Mai-Huong Tran whose telephone number is (571)-272-

1796. The examiner can normally be reached on Monday-Thursday 8:00am-6:30pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's

supervisor, David Nelms can be reached on (571) 272-1787. The fax phone numbers for

the organization where this application or proceeding is assigned are (703) 872-9306 for

regular communications and (703) 308-7722 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or

proceeding should be directed to the receptionist whose telephone number is (703) 872-

9319.

Mai-Huong Tran

David Netms
Supervisory Patent Examiner

Technology Center 2800